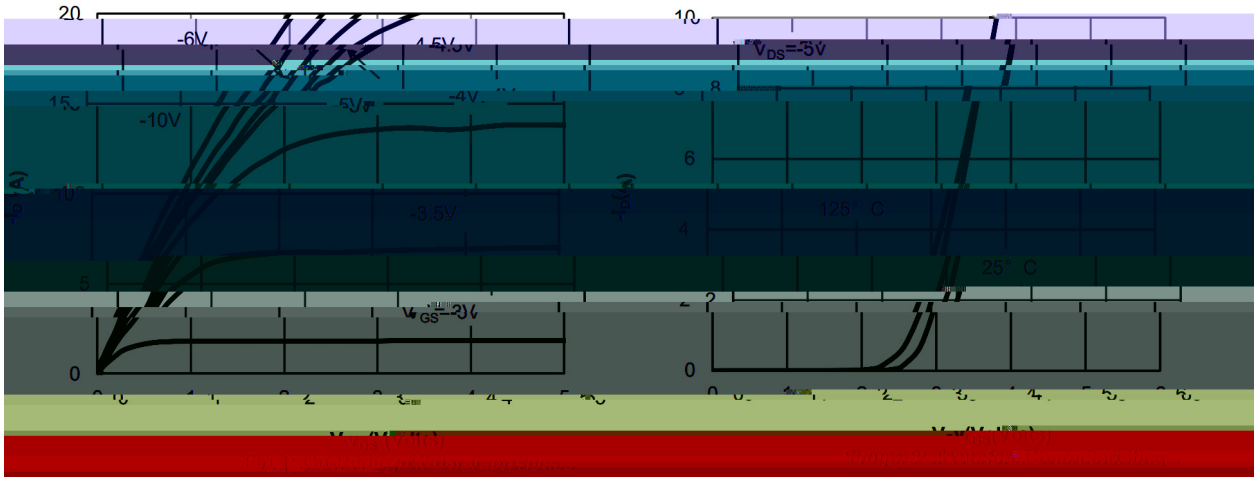
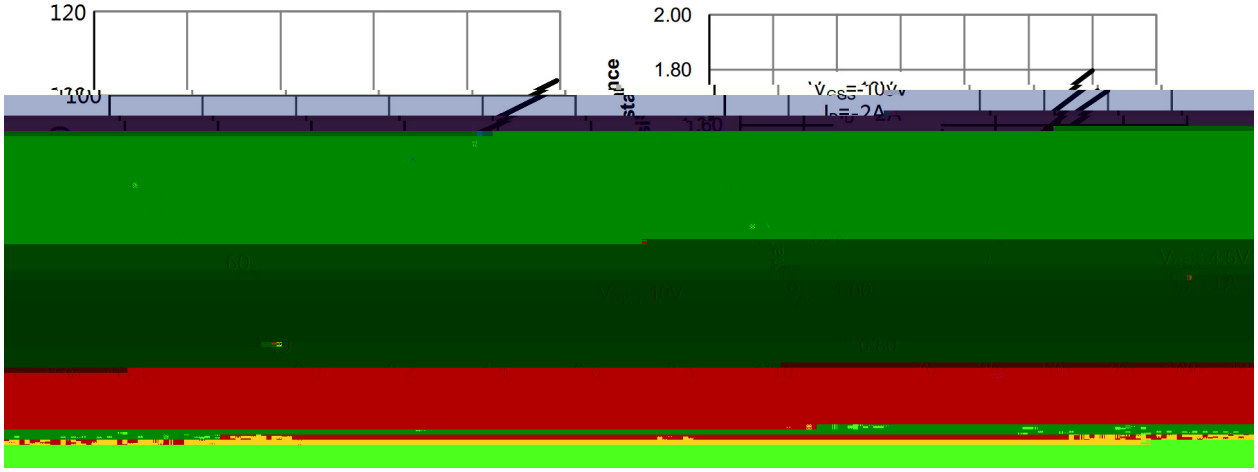
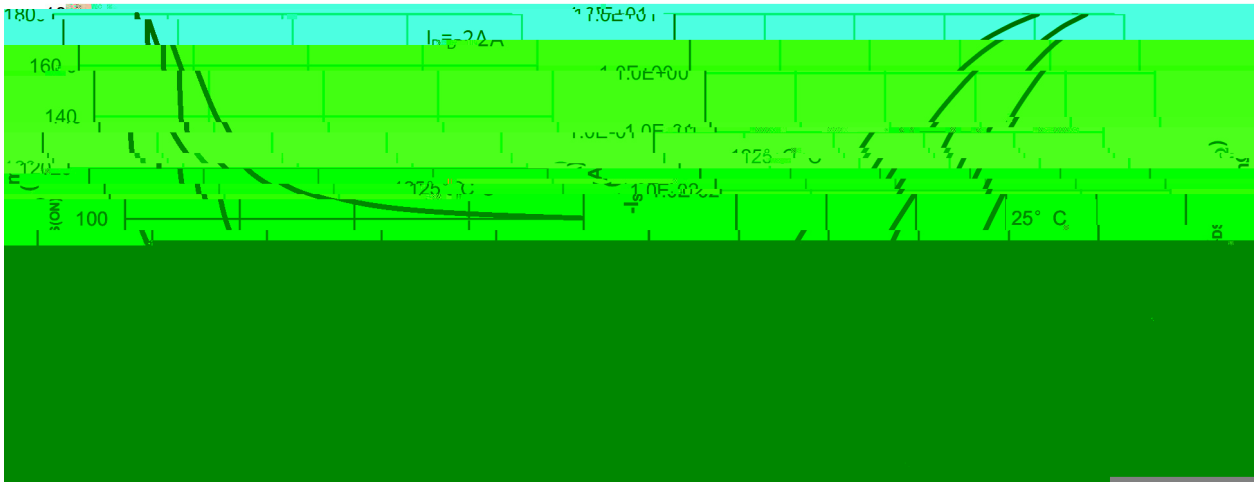
	≤			
	≤	θ		
		θ		

		μ				
		μ				
						Ω
						Ω
						μ


-6V
-4.5V
-5V
-4V
-10V
-3.5V
V_{GS}=-3V
V_{DS}=-5V
125° C
25° C


120
100
2.00
1.80
V_{GS}=-10V
I_D=-2A


160
140
100
I_D=-2A
25° C

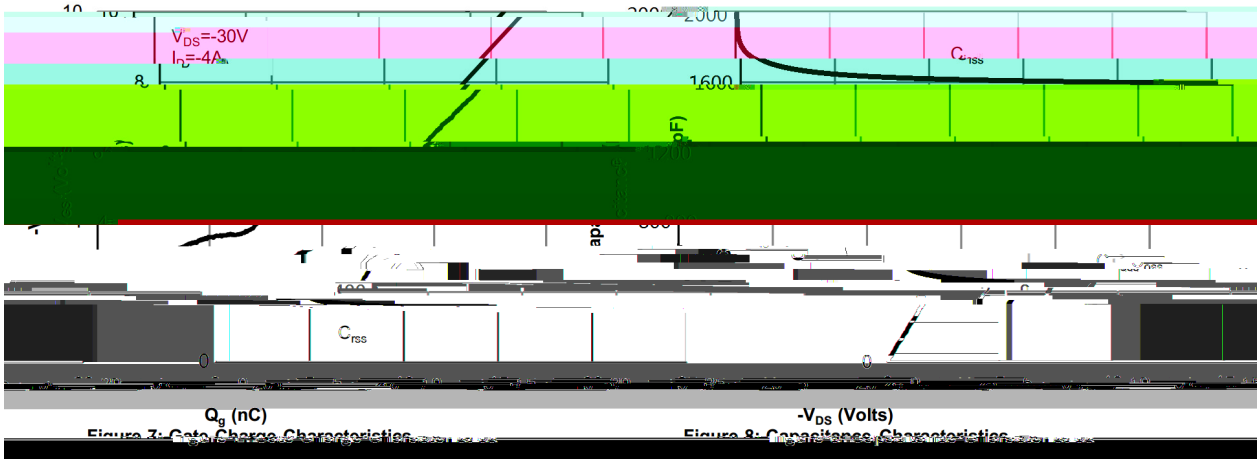
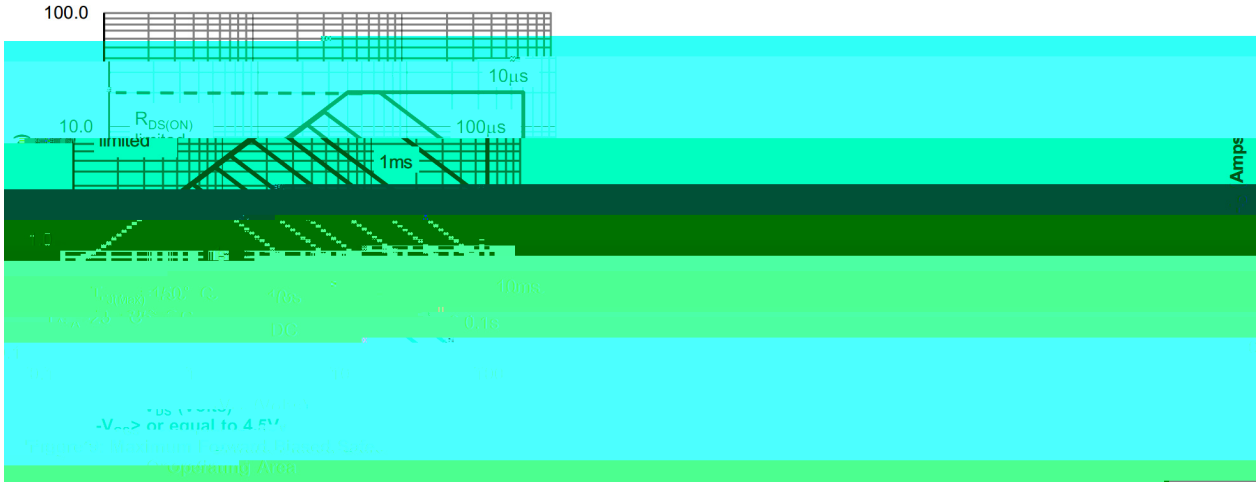
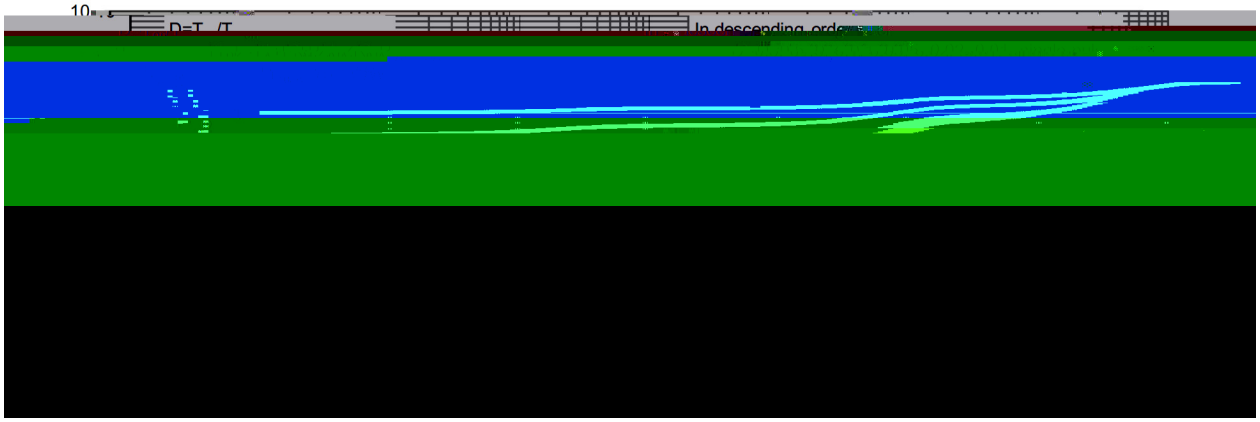
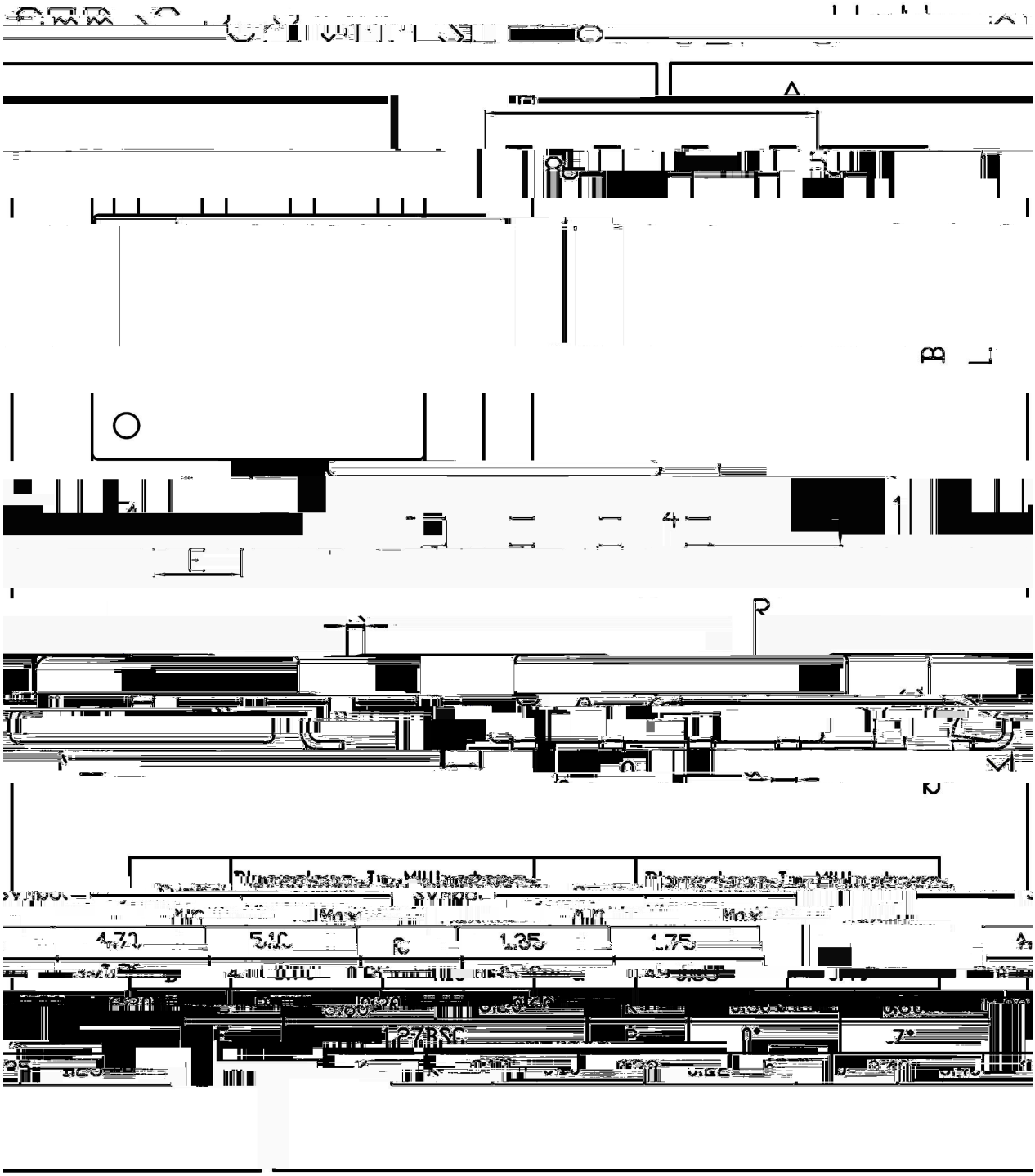


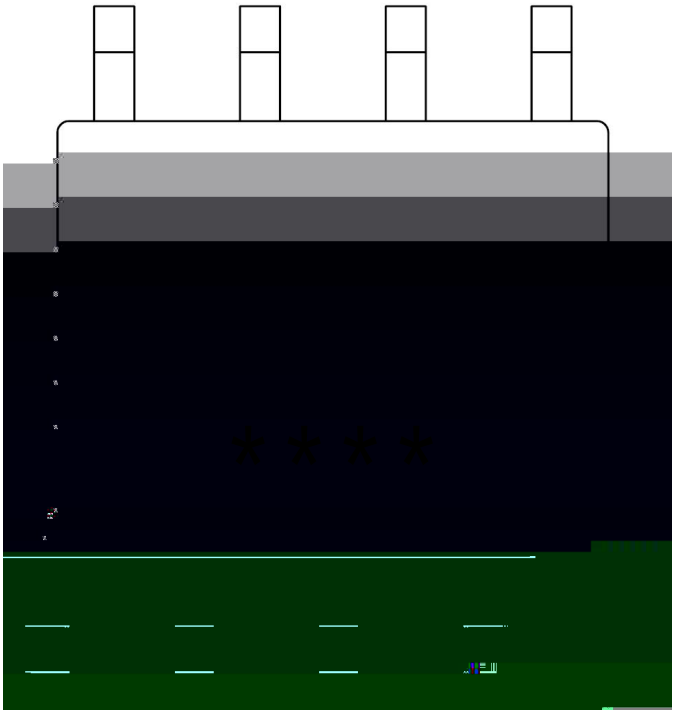
Figure 7: Gate Charge Characteristics

Figure 8: Capacitance Characteristics






SYMBOL
4.72
5.10
1.35
1.75
1.27BSC



Temperature Profile for IR Reflow Soldering(Pb-Free)